

## Thyristor Module

$$V_{RRM} = 2 \times 2400 \text{ V}$$

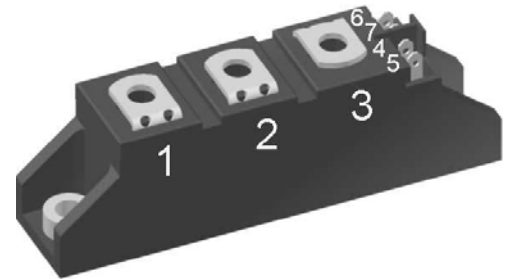
$$I_{TAV} = 104 \text{ A}$$

$$V_T = 1.46 \text{ V}$$


Phase leg

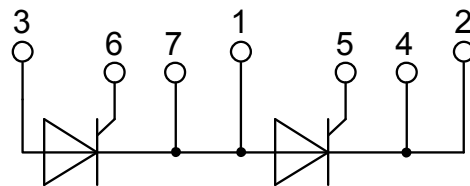
Part number

MCC94-24io1B



Backside: isolated

 E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub>-ceramic

### Applications:

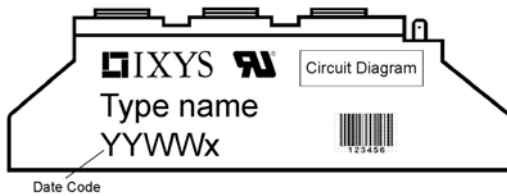
- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-240AA

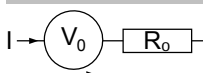
- Isolation Voltage: 3600V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Thyristor				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^{\circ}C$			2500	V	
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^{\circ}C$			2400	V	
$I_{RD}$	reverse current, drain current	$V_{RD} = 2400 V$	$T_{VJ} = 25^{\circ}C$		200	$\mu A$	
		$V_{RD} = 2400 V$	$T_{VJ} = 125^{\circ}C$		15	mA	
$V_T$	forward voltage drop	$I_T = 150 A$	$T_{VJ} = 25^{\circ}C$		1.44	V	
					1.74	V	
		$I_T = 300 A$	$T_{VJ} = 125^{\circ}C$		1.46	V	
					1.99	V	
$I_{TAV}$	average forward current	$T_C = 85^{\circ}C$	$T_{VJ} = 125^{\circ}C$		104	A	
$I_{T(RMS)}$	RMS forward current	180° sine			180	A	
$V_{T0}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 125^{\circ}C$		0.85	V	
$r_T$	slope resistance				3.2	m $\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.22	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0.20		K/W	
$P_{tot}$	total power dissipation		$T_C = 25^{\circ}C$		455	W	
$I_{TSM}$	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$		1.70	kA	
			$V_R = 0 V$		1.84	kA	
		t = 8,3 ms; (60 Hz), sine	$T_{VJ} = 125^{\circ}C$		1.45	kA	
			$V_R = 0 V$		1.56	kA	
$I^2t$	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$		14.5	kA <sup>2</sup> s	
			$V_R = 0 V$		14.0	kA <sup>2</sup> s	
		t = 8,3 ms; (60 Hz), sine	$T_{VJ} = 125^{\circ}C$		10.4	kA <sup>2</sup> s	
			$V_R = 0 V$		10.1	kA <sup>2</sup> s	
$C_J$	junction capacitance	$V_R = 700 V$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		63	pF	
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$	$T_C = 125^{\circ}C$		10	W	
		$t_p = 300 \mu s$			5	W	
$P_{GAV}$	average gate power dissipation				0.5	W	
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 125^{\circ}C$ ; f = 50 Hz	repetitive, $I_T = 250 A$		150	A/ $\mu s$	
			$t_p = 200 \mu s$ ; $di_G/dt = 0.45 A/\mu s$ ; $I_G = 0.45 A$ ; $V_D = \frac{2}{3} V_{DRM}$	non-repet., $I_T = 104 A$		500	A/ $\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V_D = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$T_{VJ} = 125^{\circ}C$		1000	V/ $\mu s$	
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$		1.5	V	
			$T_{VJ} = -40^{\circ}C$		1.6	V	
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$		150	mA	
			$T_{VJ} = -40^{\circ}C$		200	mA	
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^{\circ}C$		0.25	V	
$I_{GD}$	gate non-trigger current				10	mA	
$I_L$	latching current	$t_p = 10 \mu s$	$T_{VJ} = 25^{\circ}C$		200	mA	
		$I_G = 0.45 A$ ; $di_G/dt = 0.45 A/\mu s$					
$I_H$	holding current	$V_D = 6 V$ $R_{GK} = \infty$	$T_{VJ} = 25^{\circ}C$		150	mA	
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^{\circ}C$		2	$\mu s$	
		$I_G = 0.45 A$ ; $di_G/dt = 0.45 A/\mu s$					
$t_q$	turn-off time	$V_R = 100 V$ ; $I_T = 150 A$ ; $V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^{\circ}C$		185	$\mu s$	
		$di/dt = 10 A/\mu s$ ; $dv/dt = 20 V/\mu s$ ; $t_p = 200 \mu s$					

Package TO-240AA				Ratings		
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			200	A
$T_{stg}$	storage temperature		-40		125	°C
$T_{VJ}$	virtual junction temperature		-40		125	°C
<b>Weight</b>				90		g
$M_D$	mounting torque		2.5		4	Nm
$M_T$	terminal torque		2.5		4	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	13.0	9.7		mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0		mm
$V_{ISOL}$	isolation voltage	t = 1 second		3600		V
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000		V

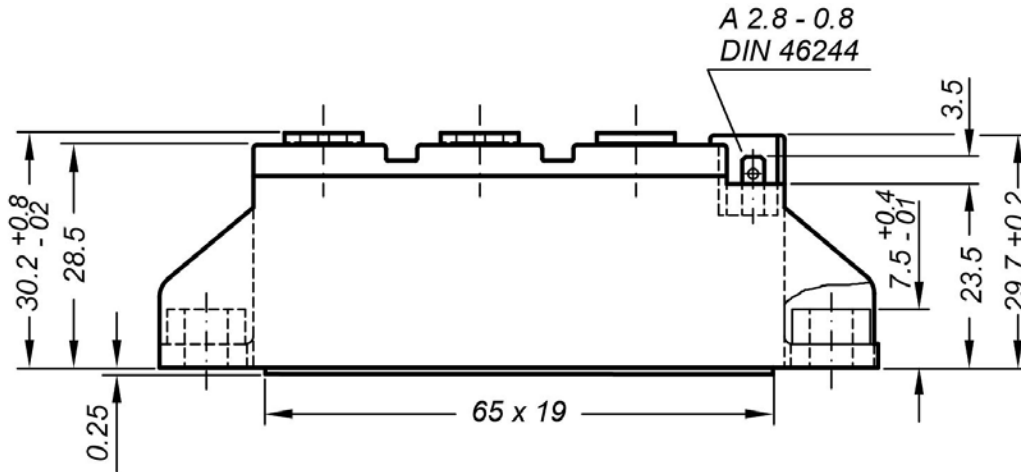


Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCC94-24io1B	MCC94-24io1B	Box	6	508871

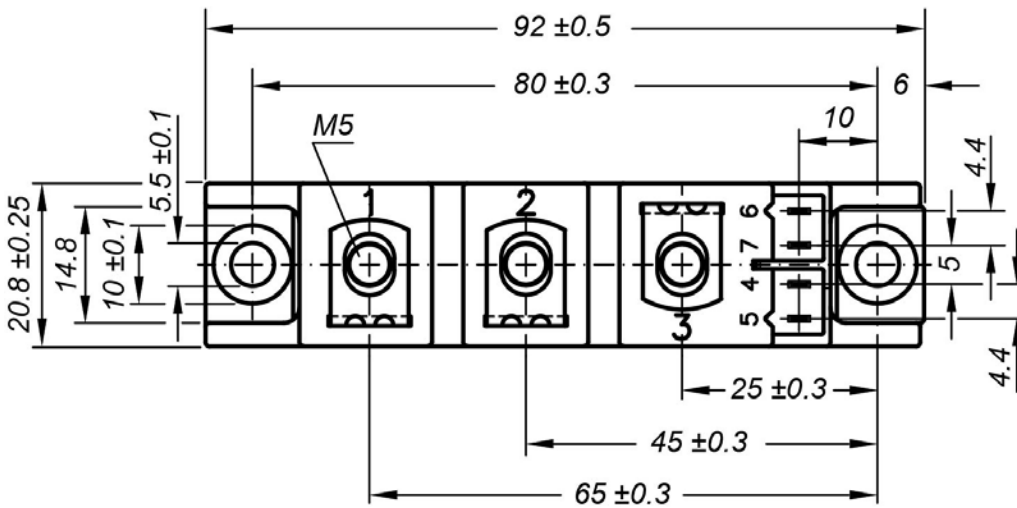
**Equivalent Circuits for Simulation**
*\* on die level*
 $T_{VJ} = 125^\circ\text{C}$ 

**Thyristor**

$V_{0\ max}$	threshold voltage	0.85	V
$R_{0\ max}$	slope resistance *	2	mΩ

**Outlines TO-240AA**



General tolerance: DIN ISO 2768 class „c“



Optional accessories: Keyed gate/cathode twin plugs  
 Wire length: 350 mm, gate = white, cathode = red  
 UL 758, style 3751  
 Type **ZY 200L** (L = Left for pin pair 4/5)  
 Type **ZY 200R** (R = Right for pin pair 6/7)



**Thyristor**

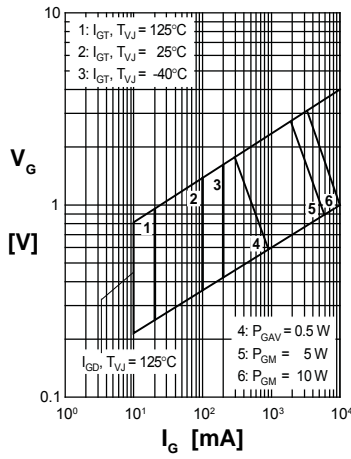


Fig. 1 Gate trigger characteristics

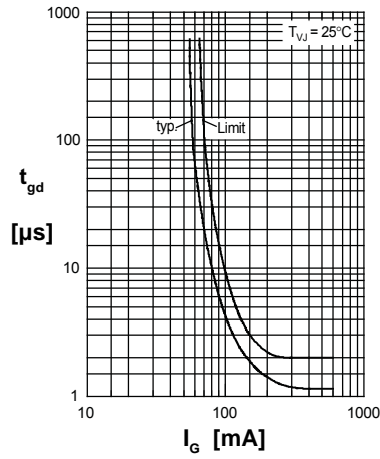


Fig. 2 Gate trigger delay time